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Transistors

Power management (dual digital transistors) UMC2N / FMC2A

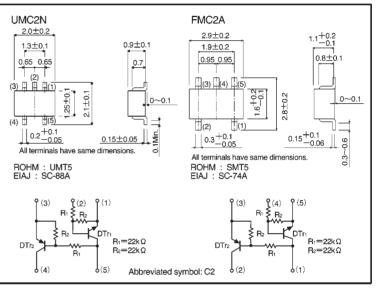
Features

- Includes a DTA124E and a DTC124E transistor in a single UMT and a SMT package.
- 2) Ideal for power switch circuits.
- 3) Mounting cost and area can be cut in half.
- Structure

A PNP and a NPN digital transistor (each with two built in resistors)

The following characteristics apply to both the DTr_1 and DTr_2 , however, the "–" sign on DTr_2 values for the PNP type have been omitted.





•Absolute maximum ratings (Ta = 25° C)

| Parameter | | Symbol | Limits | Unit | |
|----------------------|-------|----------|--------------|----------------|--|
| Supply voltage | | Vcc | 50 | V | |
| Input current | | Vin | 40 | v | |
| | | VIN | -10 | ` | |
| Output current | | lo | 30 | mA | |
| | | IC(Max.) | Ic(Max.) 100 | | |
| Power dissipation | UMC2N | Pd | 150(TOTAL) | *1 mW *2 | |
| | FMC2A | Fu Fu | 300(TOTAL) | | |
| Junction temperature | | Tj | 150 | ĉ | |
| Storage temperature | | Tstg | -55~+150 | ĉ | |

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.



Electrical characteristics (Ta = 25°C)

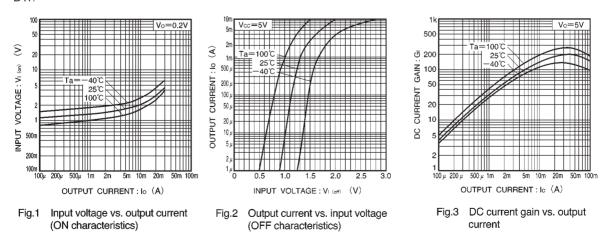
| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions | |
|----------------------|--------------------------------|------|------|------|------|-------------------------------|--|
| Input voltage | VI (off) | _ | — | 0.5 | v | Vcc=5V, lo=100 μ A | |
| input voltage | VI (on) | 3 | — | — | | Vo=0.2V, Io=5mA | |
| Output voltage | Vo(on) | _ | 0.1 | 0.3 | V | lo/li=10mA/0.5mA | |
| Input current | h | — | — | 0.36 | mA | V1=5V | |
| Output current | IO (off) | — | _ | 0.5 | μA | Vcc=50V, Vi=0V | |
| DC current gain | Gi | 56 | _ | — | — | Vo=5V, lo=5mA | |
| Transition frequency | fτ | _ | 250 | _ | MHz | Vce=10mA, Ie=-5mA, f=100MHz * | |
| Input resistance | Rı | 15.4 | 22 | 28.6 | kΩ | | |
| Resistance ratio | R ₂ /R ₁ | 0.8 | 1 | 1.2 | — | | |

* Transition frequency of the device

Packaging specifications

| | Packaging type | Taping | |
|----------|------------------------------|--------|------|
| | Code | TR | T148 |
| Part No. | Basic ordering unit (pieces) | 3000 | 3000 |
| UMC2N | | 0 | — |
| FMC2A | | _ | 0 |

•Electrical characteristic curves DTr₁



ROHM

Transistors

